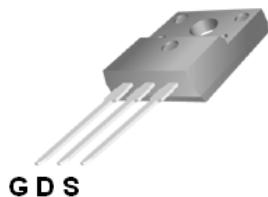


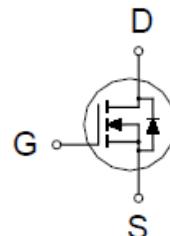
P1350ATF / P1350ATFS N-Channel Enhancement Mode MOSFET

PRODUCT SUMMARY

$V_{(BR)DSS}$	$R_{DS(ON)}$	I_D
500V	0.52Ω @ $V_{GS} = 10V$	13A



TO-220F
TO-220FS



100% UIS tested

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ C$ Unless Otherwise Noted)

PARAMETERS/TEST CONDITIONS		SYMBOL	LIMITS	UNITS
Drain-Source Voltage		V_{DS}	500	V
Gate-Source Voltage		V_{GS}	± 30	
Continuous Drain Current ²	$T_C = 25^\circ C$	I_D	13	A
	$T_C = 100^\circ C$		10	
Pulsed Drain Current ^{1, 2}		I_{DM}	45	
Avalanche Current ³		I_{AS}	8.8	
Avalanche Energy ³	$L = 10mH$	E_{AS}	387	mJ
Power Dissipation	$T_C = 25^\circ C$	P_D	34	W
	$T_C = 100^\circ C$		13	
Operating Junction & Storage Temperature Range		T_J, T_{STG}	-55 to 150	°C

THERMAL RESISTANCE RATINGS

THERMAL RESISTANCE	SYMBOL	TYPICAL	MAXIMUM	UNITS
Junction-to-Case	$R_{\theta JC}$	3.6	3.6	°C / W
Junction-to-Ambient	$R_{\theta JA}$		62.5	

¹Pulse width limited by maximum junction temperature.

²Limited only by maximum temperature allowed.

³ $V_{DD} = 50V$, starting $T_J = 25^\circ C$

P1350ATF / P1350ATFS

N-Channel Enhancement Mode MOSFET

ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$, Unless Otherwise Noted)

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN	TYP	MAX	
STATIC						
Drain-Source Breakdown Voltage	$V_{(\text{BR})\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_D = 250\mu\text{A}$	500			V
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_D = 250\mu\text{A}$	2.5		4.5	
Gate-Body Leakage	I_{GSS}	$V_{\text{DS}} = 0\text{V}, V_{\text{GS}} = \pm 30\text{V}$			± 100	nA
Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}} = 500\text{V}, V_{\text{GS}} = 0\text{V}, T_J = 25^\circ\text{C}$			25	μA
		$V_{\text{DS}} = 500\text{V}, V_{\text{GS}} = 0\text{V}, T_J = 100^\circ\text{C}$			250	
Drain-Source On-State	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}} = 10\text{V}, I_D = 6.5\text{A}$		0.4	0.52	Ω
Forward Transconductance ¹	g_{fs}	$V_{\text{DS}} = 40\text{V}, I_D = 6\text{A}$		8.5		S
DYNAMIC						
Input Capacitance	C_{iss}	$V_{\text{GS}} = 0\text{V}, V_{\text{DS}} = 25\text{V}, f = 1\text{MHz}$		2185		pF
Output Capacitance	C_{oss}			204		
Reverse Transfer Capacitance	C_{rss}			59		
Total Gate Charge ²	Q_g	$V_{\text{DS}} = 250\text{V}, V_{\text{GS}} = 10\text{V}, I_D = 6\text{A}$		40		nC
Gate-Source Charge ²	Q_{gs}			11.5		
Gate-Drain Charge ²	Q_{gd}			12.5		
Turn-On Delay Time ²	$t_{\text{d}(\text{on})}$	$V_{\text{DD}} = 250\text{V}, I_D = 6\text{A}, R_G = 4.7\Omega$		30		nS
Rise Time ²	t_r			25		
Turn-Off Delay Time ²	$t_{\text{d}(\text{off})}$			43		
Fall Time ²	t_f			15		
SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS ($T_J = 25^\circ\text{C}$)						
Continuous Current ³	I_S				13	A
Forward Voltage ¹	V_{SD}	$I_F = 4\text{A}, V_{\text{GS}} = 0\text{V}$			1.7	V
Reverse Recovery Time	t_{rr}	$V_{\text{GS}} = 0\text{V}, I_F = 12\text{A}, dI/dt = 100\text{A}/\mu\text{s}$		320		nS
Reverse Recovery Charge	Q_{rr}			4.9		μC

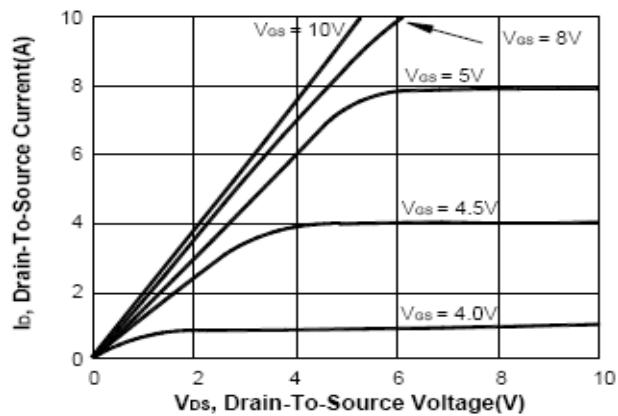
¹Pulse test : Pulse Width $\leq 300\ \mu\text{sec}$, Duty Cycle $\leq 2\%$.

²Independent of operating temperature.

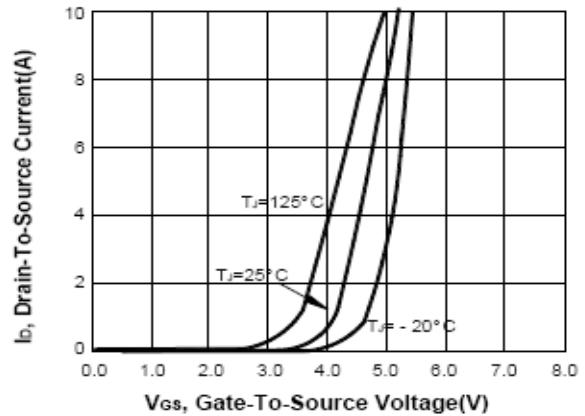
³ Pulse width limited by maximum junction temperature.

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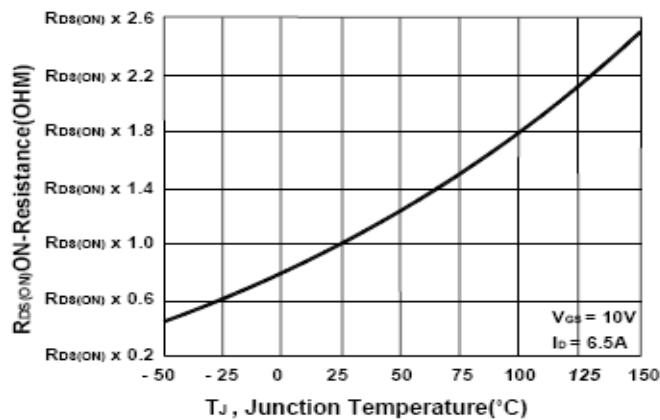
Output Characteristics



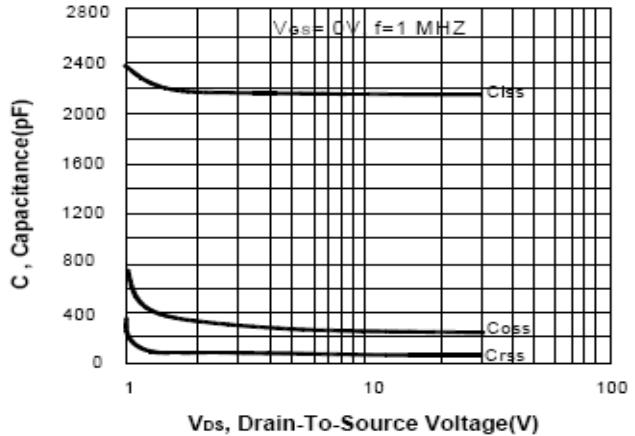
Transfer Characteristics



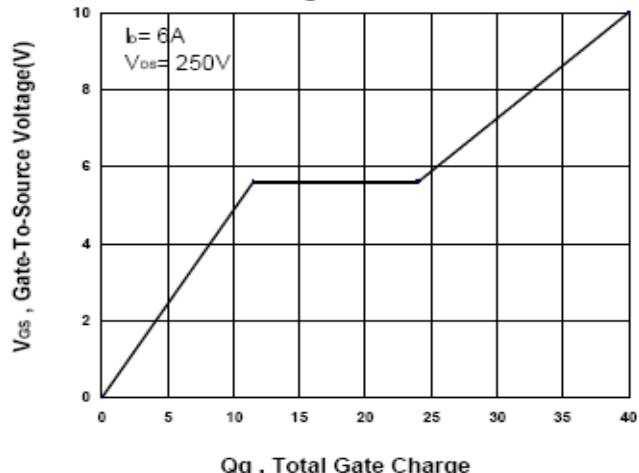
On-Resistance VS Temperature



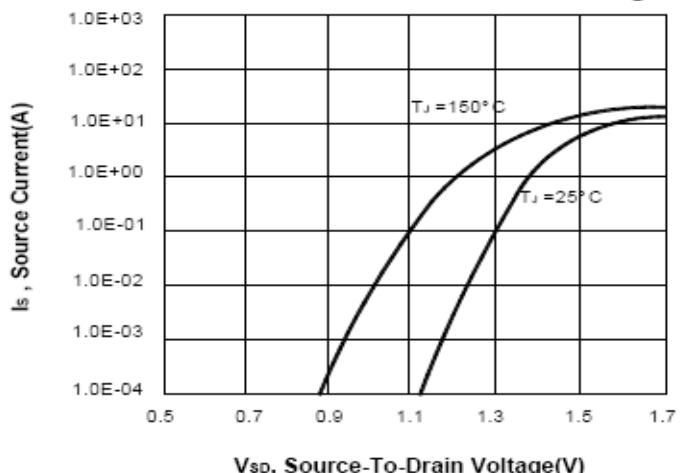
Capacitance Characteristic



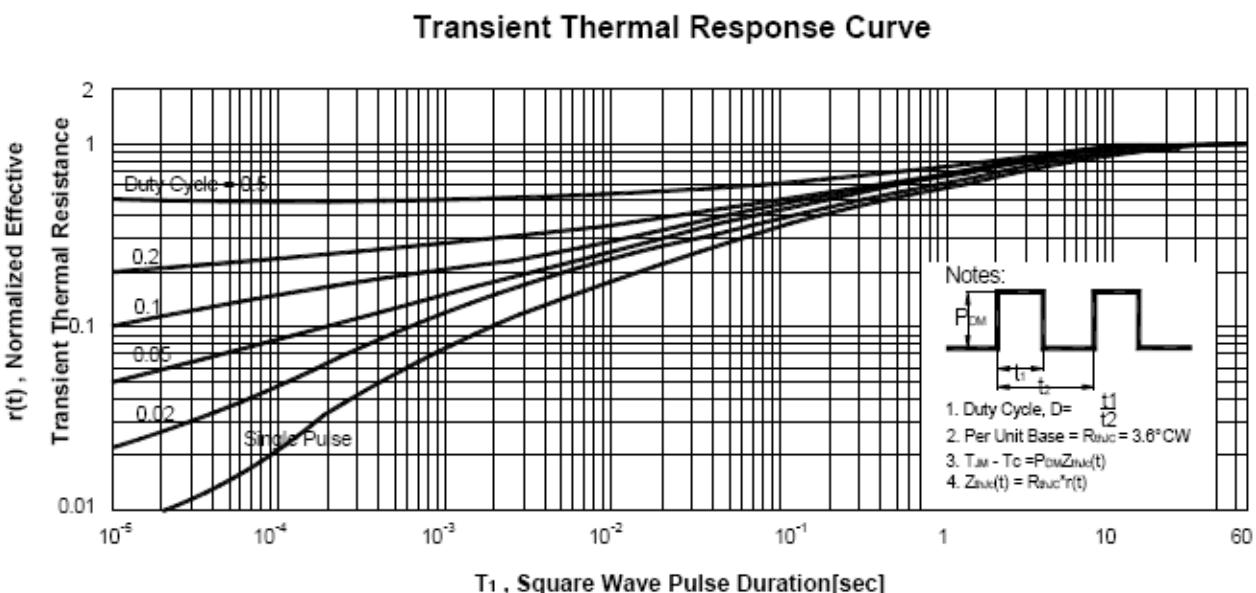
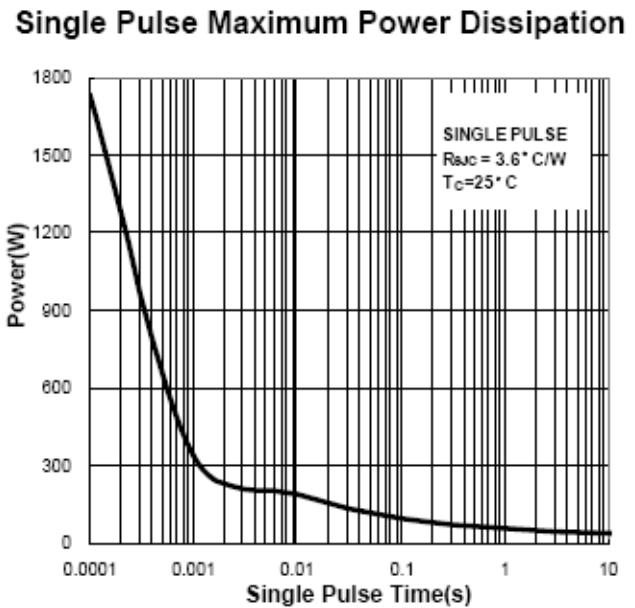
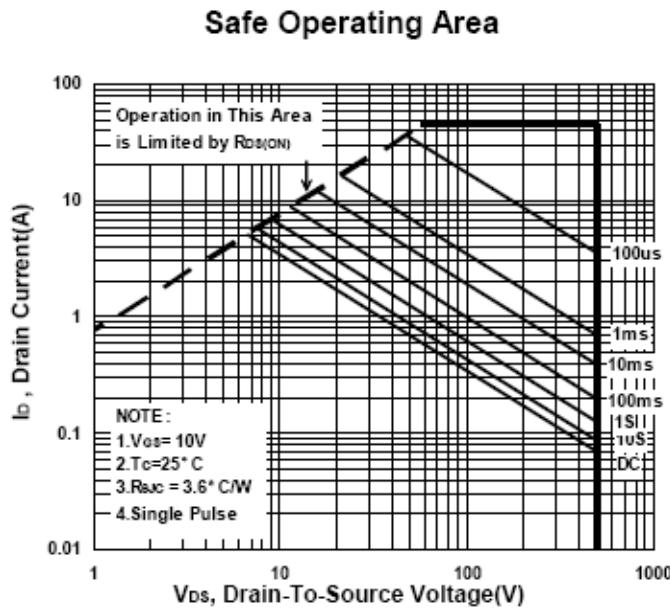
Gate charge Characteristics



Source-Drain Diode Forward Voltage



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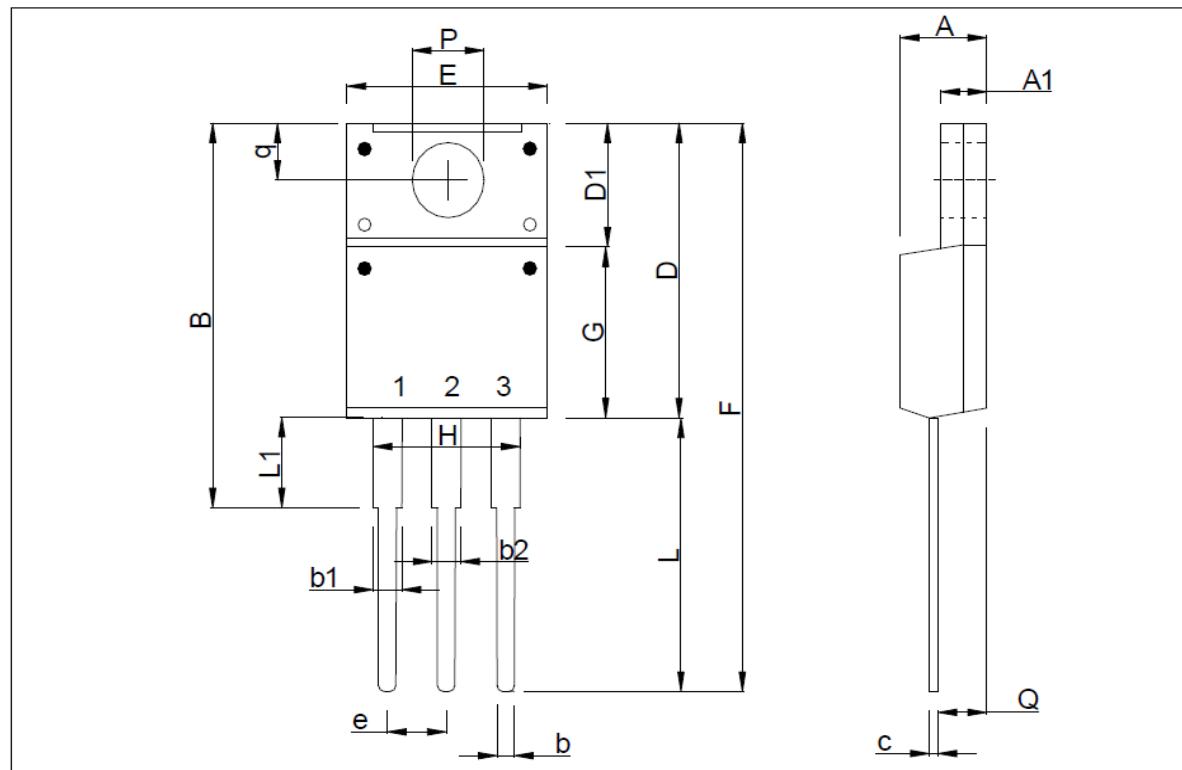


P1350ATF / P1350ATFS N-Channel Enhancement Mode MOSFET

Package Dimension

TO-220F (3-Lead) MECHANICAL DATA

Dimension	mm			Dimension	mm		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A	4.2		4.93	e	2.05	2.55	3.05
A1	2.34		3.1	F	27.45		30.6
B	17.77		20.3	G	7.72		9.3
b	0.6		1.05	H	6.1		7.1
b1	0.9	1.23	1.62	L	12.5		14.5
b2	0.6		1.9	L1	1.97		3.8
c	0.4		1.0	P	2.98		3.4
D	14.7		16.4	Q	2.1		2.96
D1	6.4		7.5	q	3.0		3.8
E	9.7		10.4				



P1350ATF / P1350ATFS N-Channel Enhancement Mode MOSFET

Package Dimension

TO-220FS (3-Lead) MECHANICAL DATA

Dimension	mm			Dimension	mm		
	Min.	Typ.	Max.		Min.	Typ.	Max.
A	4.2	4.7	4.93	e	2.05	2.54	3.05
A1	2.34	2.8	3.1	F	28.04		30.3
B	17.7		20.3	G	8.2	8.87	9.57
b	0.65	0.8	1.05	L	12.37		14.3
b1	0.9	1.3	1.5	L1	1.4	2.3	2.5
c	0.4	0.7	1.0	P	2.98	3.2	3.4
D	15.37		16.3	Q	2.1	2.6	2.96
D1	5.5		7.5	q	3.0	3.5	3.8
E	9.7	10.16	10.36				

